

MBRA210ET3

This device employs the Schottky Barrier principle in a metal-to-silicon power rectifier. Features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency switching power supplies; free wheeling diodes and polarity protection diodes. Typical applications are AC/DC and DC-DC converters, reverse battery protection, and "Oring" of multiple supply voltages and any other application where performance and size are critical.

Features

- Low I_R, Extends Battery Life
- 1st in the Market Place with a 10 V_R Schottky Rectifier
- Compact Package with J-Bend Leads Ideal for Automated Handling
- Highly Stable Oxide Passivated Junction
- Guardring for Over-Voltage Protection
- Optimized for Low Leakage Current
- Pb-Free Package is Available

Mechanical Characteristics

- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 70 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Polarity Band Indicates Cathode Lead
- ESD Ratings:

Machine Model = C Human Body Model = 3B

Surface Mount Schottky Power Rectifier

SMA Power Surface Mount Package

SCHOTTKY BARRIER RECTIFIER 2 AMPERES 10 VOLTS



SMA CASE 403D PLASTIC

MARKING DIAGRAM



B2E1 = Device Code A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]		
MBRA210ET3	SMA	5000/Tape & Reel		
MBRA210ET3G	SMA (Pb-Free)	5000/Tape & Reel		

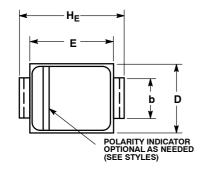
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



PACKAGE DIMENSIONS

SMA

CASE 403D-02 ISSUE D



NOTES:

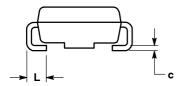
- NOTES:

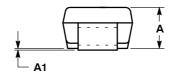
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

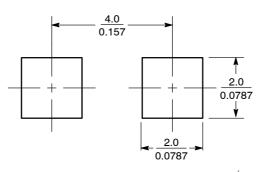
 3. 403D-01 OBSOLETE, NEW STANDARD IS 403D-02.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.92	2.17	2.27	0.076	0.085	0.089
A1	0.05	0.10	0.15	0.002	0.004	0.006
b	1.27	1.45	1.63	0.050	0.057	0.064
С	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
E	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060





SOLDERING FOOTPRINT*



 $\left(\frac{\text{mm}}{\text{inches}}\right)$ SCALE 8:1

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.